

1. Product profile

1.1 General description

Ultrafast epitaxial rectifier diode in a SOT226 (I2PAK) plastic package.

1.2 Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward voltage drop
- Low profile package facilitates compact/slim designs
- Low switching losses
- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations

1.3 Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

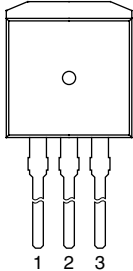
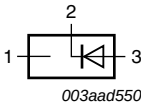
1.4 Quick reference data

Table 1. Quick reference

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \leq 135\text{ }^{\circ}\text{C}$; see Figure 1 and 2	-	-	5	A
Dynamic characteristics						
t_{rr}	reverse recovery time	$I_F = 1\text{ A}$; $V_R \geq 30\text{ V}$; $dI_F/dt = 100\text{ A}/\mu\text{s}$; $T_j = 25\text{ }^{\circ}\text{C}$; see Figure 5	-	50	60	ns

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	 SOT226A (I2PAK)	
2	K	cathode		
3	A	anode		
mb	K	mounting base; cathode		

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BYV25G-600	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	$T_{mb} \leq 100\text{ °C}$; DC	-	600	V
$I_{F(AV)}$	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \leq 135\text{ °C}$; see Figure 1 and 2	-	5	A
I_{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \leq 135\text{ °C}$	-	10	A
I_{FSM}	non-repetitive peak forward current	$t_p = 8.3\text{ ms}$; sine-wave pulse; $T_{j(\text{init})} = 25\text{ °C}$	-	66	A
		$t_p = 10\text{ ms}$; sine-wave pulse; $T_{j(\text{init})} = 25\text{ °C}$	-	60	A
T_{stg}	storage temperature		-40	150	°C
T_j	junction temperature		-	150	°C

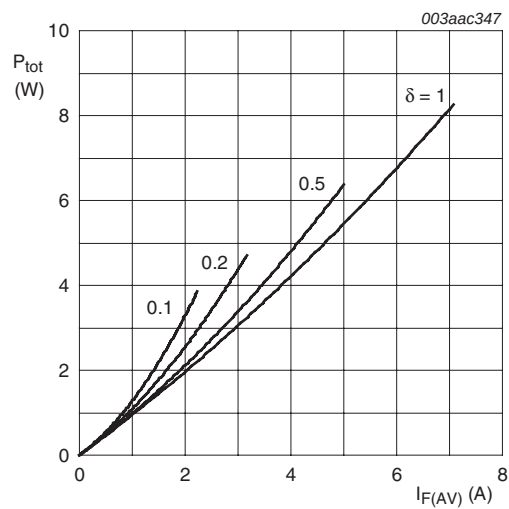


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

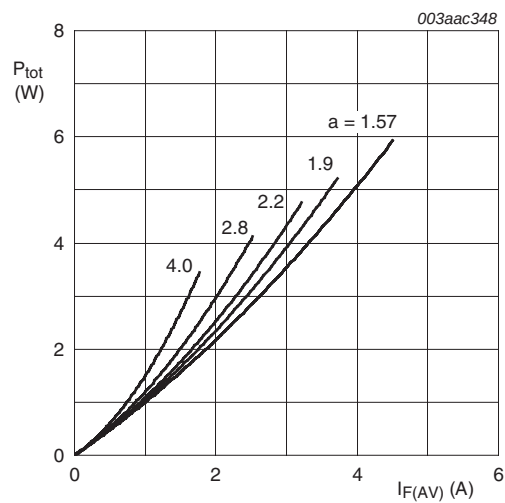


Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; see Figure 3	-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	60	-	K/W

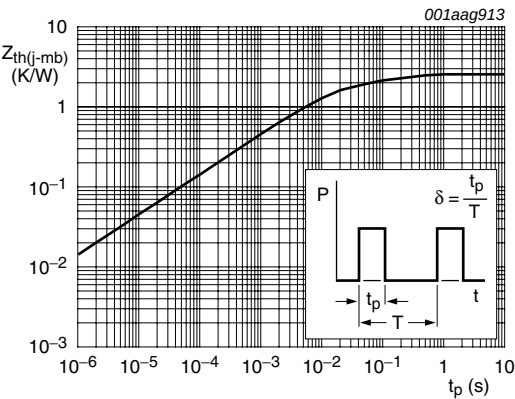
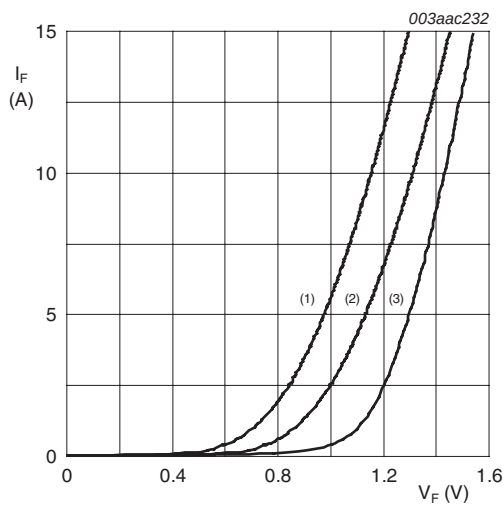


Fig 3. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V_F	forward voltage	$I_F = 5\text{ A}$; see Figure 4	-	1.12	1.3	V
		$I_F = 5\text{ A}$; $T_{mb} \leq 150\text{ °C}$; see Figure 4	-	0.97	1.11	V
I_R	reverse current	$V_R = 600\text{ V}$; $T_j = 100\text{ °C}$	-	0.1	0.35	mA
		$V_R = 600\text{ V}$	-	2	50	μA
Dynamic characteristics						
Q_r	recovered charge	$I_F = 2\text{ A}$; $V_R \geq 30\text{ V}$; $dI_F/dt = 20\text{ A}/\mu\text{s}$; see Figure 5	-	40	70	nC
t_{rr}	reverse recovery time	$I_F = 1\text{ A}$; $V_R \geq 30\text{ V}$; $dI_F/dt = 100\text{ A}/\mu\text{s}$; $T_j = 25\text{ °C}$; see Figure 5	-	50	60	ns
V_{FR}	forward recovery voltage	$I_F = 10\text{ A}$; $dI_F/dt = 10\text{ A}/\mu\text{s}$; see Figure 6	-	3.2	-	V
I_{RM}	peak reverse recovery current	$I_F = 10\text{ A}$; $V_R \leq 30\text{ V}$; $dI_F/dt = 50\text{ A}/\mu\text{s}$; $T_j = 100\text{ °C}$; see Figure 5	-	3	5.5	A



- (1) $T_j = 150\text{ °C}$; typical values
- (2) $T_j = 150\text{ °C}$; maximum values
- (3) $T_j = 25\text{ °C}$; maximum values

Fig 4. Forward current as a function of forward voltage

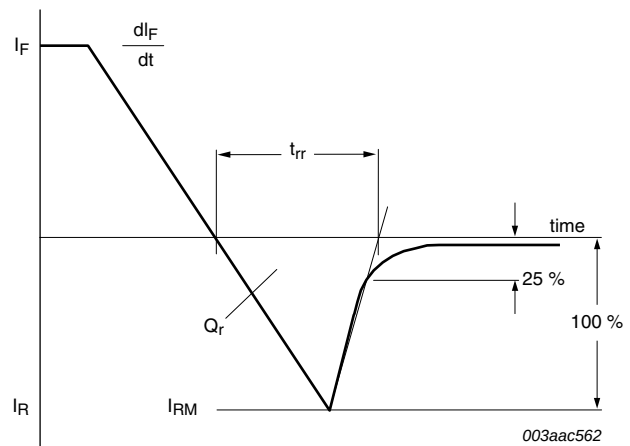


Fig 5. Reverse recovery definitions; ramp recovery

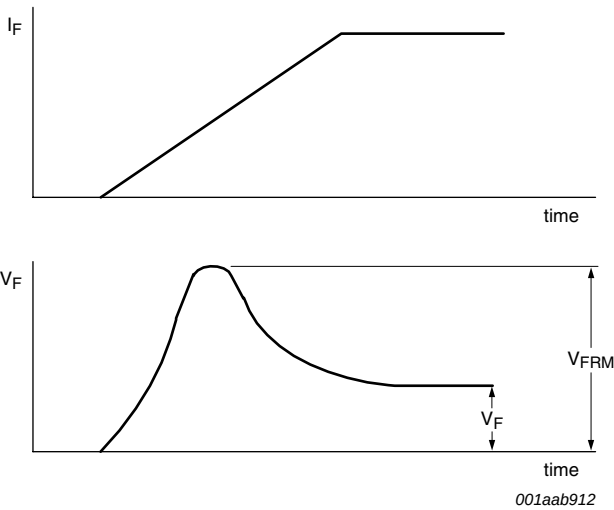


Fig 6. Forward recovery definitions

7. Package outline

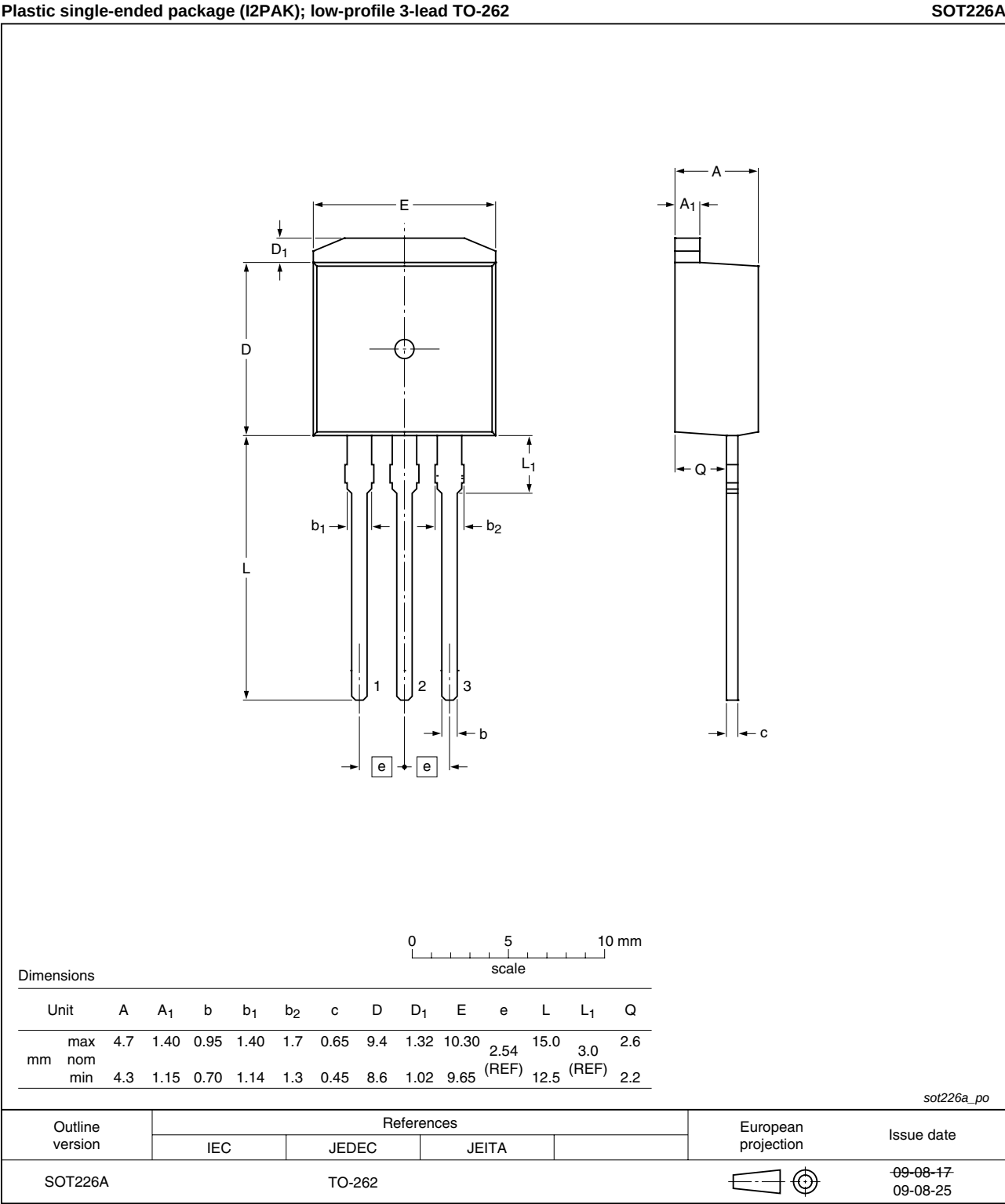


Fig 7. Package outline SOT226A (I2PAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV25G-600_1	20100204	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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